

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

 $0.32^{+0.1}_{-0.05}$

2.8 ±0.2

DESCRIPTION

The μ PA1914 is a switching device which can be driven directly by a 4 V power source.

The μ PA1914 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 4 V power source
- · Low on-state resistance

 $R_{DS(on)1} = 57 \text{ m}\Omega \text{ MAX.}$ (Vgs = -10 V, ID = -2.5 A) $R_{DS(on)2} = 86 \text{ m}\Omega \text{ MAX.}$ (VGS = -4.5 V, ID = -2.5 A) $R_{DS(on)3} = 96 \text{ m}\Omega \text{ MAX.}$ (Vgs = -4.0 V, ID = -2.5A)

ORDERING INFORMATION

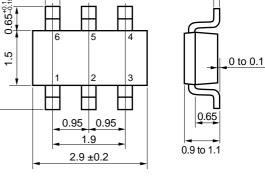
PART NUMBER	PACKAGE
μΡΑ1914ΤΕ	6-pin Mini Mold (Thin Type)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage	Vdss	-30	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	D(DC)	±4.5	А
Drain Current (pulse) Note1	D(pulse)	±18	А
Total Power Dissipation	P T1	0.2	W
Total Power Dissipation Note2	Рт2	2	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

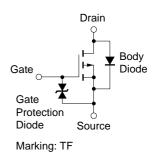
0.16+0.1

PACKAGE DRAWING (Unit : mm)



1, 2, 5, 6 : Drain : Gate 3 4 : Source

EQUIVALENT CIRCUIT



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

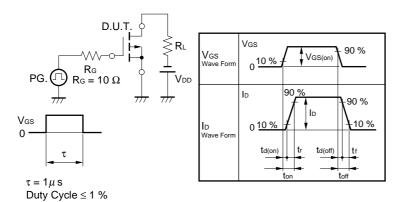
- **2.** Mounted on FR-4 Board, $t \le 5$ sec.
- The diode connected between the gate and source of the transistor serves as a protector against ESD. Remark When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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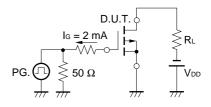
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	loss	$V_{DS} = -30 V, V_{GS} = 0 V$			-10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 16 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	$V_{DS} = -10 V$, $I_{D} = -1 mA$	-1.0	-1.6	-2.5	V
Forward Transfer Admittance	yfs	$V_{DS} = -10 V$, $I_D = -2.5 A$	1	7.1		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 V$, $I_D = -2.5 A$		43	57	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, \text{ Id} = -2.5 \text{ A}$		58	86	mΩ
	RDS(on)3	$V_{GS} = -4.0 \text{ V}, \text{ Id} = -2.5 \text{ A}$		64	96	mΩ
Input Capacitance	Ciss	$V_{DS} = -10 V$		589		pF
Output Capacitance	Coss	Vgs = 0 V		210		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		86		pF
Input Capacitance	Ciss	V _{DS} = -25 V		546		pF
Output Capacitance	Coss	Vgs = 0 V		148		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		65		pF
Turn-on Delay Time	td(on)	$V_{DD} = -15 V$		16		ns
Rise Time	tr	ID = -2.5 A		57		ns
Turn-off Delay Time	td(off)	$V_{GS(on)} = -10 V$		63		ns
Fall Time	tr	Rg = 10 Ω		80		ns
Total Gate Charge	QG	Vdd= -24 V		11		nC
Gate to Source Charge	QGS	ID = -4.5 A		1.5		nC
Gate to Drain Charge	Qgd	V _{GS} = -10 V		2.8		nC
Diode Forward Voltage	VF(S-D)	IF = 4.5 A, VGS = 0 V		0.88		V
Reverse Recovery Time	trr	IF = 4.5 A, VGS = 0 V		22		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		11		nC

TEST CIRCUIT 1 SWITCHING TIME

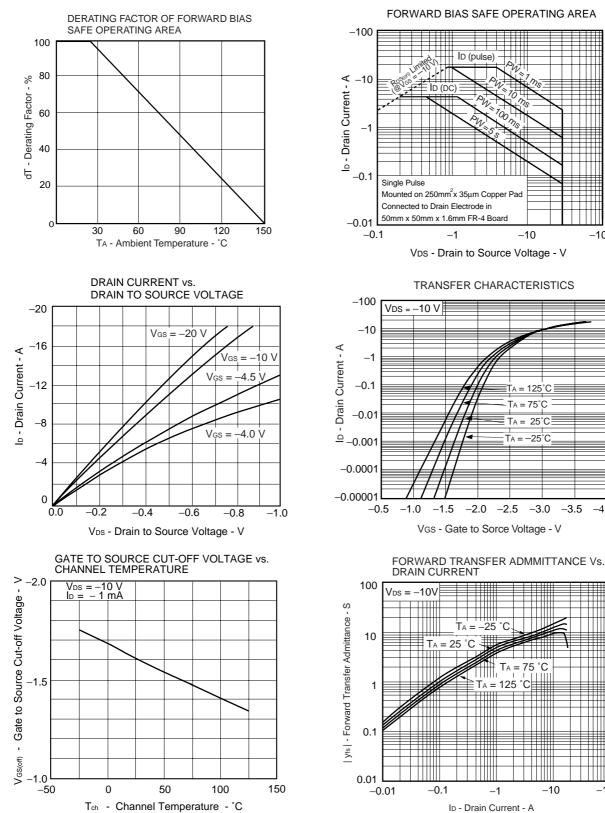


TEST CIRCUIT 2 GATE CHARGE



-100

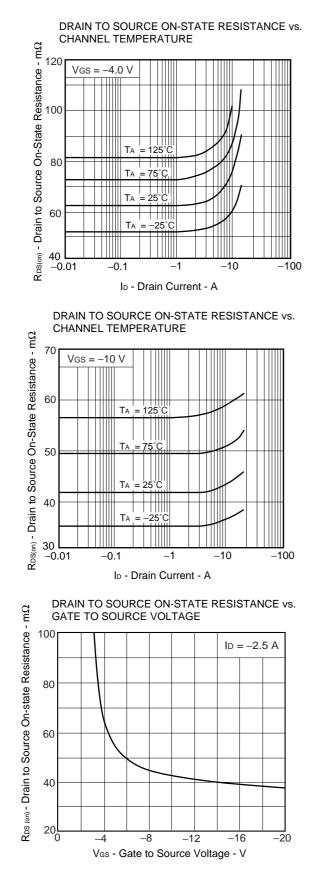
-4.0



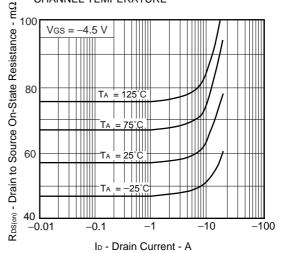
TYPICAL CHARACTERISTICS (TA = 25°C)

Data Sheet D13810EJ1V0DS00

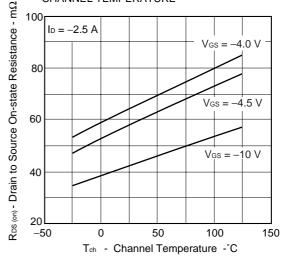
-100

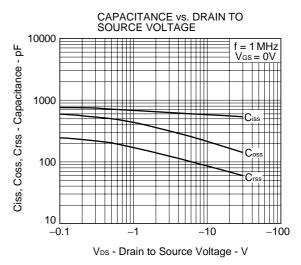


DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



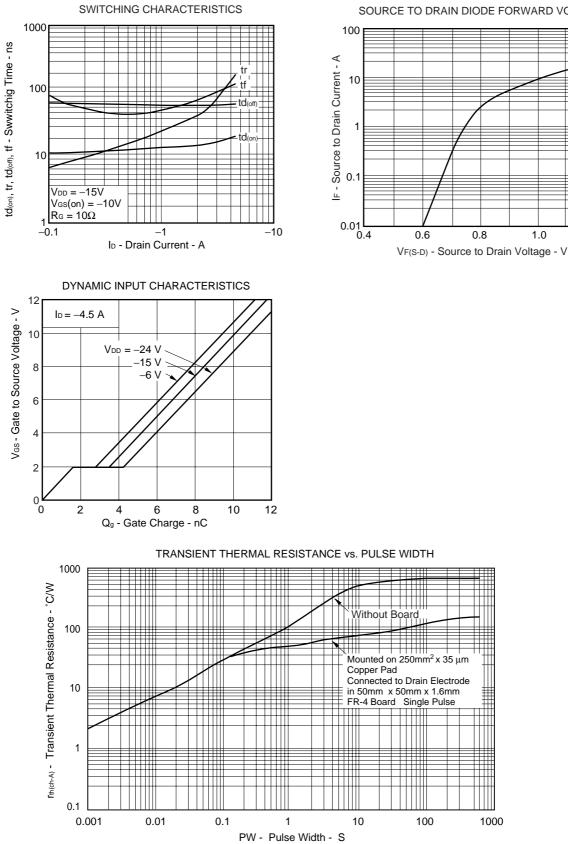
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE





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SOURCE TO DRAIN DIODE FORWARD VOLTAGE

1.0

1.2

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